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Hyperfast Rectifier, 60 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS									
I _{F(AV)} 60 A									
V _R	1200 V								
V _F at I _F at 125 °C	1.7 V								
t _{rr}	38 ns								
T _J max.	175 °C								
Package	TO-247AD 2L								
Circuit configuration	Single								

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- · Polyimide passivation
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminals**: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage	V _{RRM}		1200	V					
Average rectified forward current	I _{F(AV)}	T _C = 111 °C, D = 0.50	60						
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	425	A					
Repetitive peak forward current	I _{FRM}	T _C = 111 °C, D = 0.50, f = 20 kHz	120						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)										
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNIT										
Breakdown voltage, blocking voltage		I _R = 100 μA	1200	-	-					
Forward voltage	V _F	I _F = 60 A	-	1.9	2.5	V				
Forward voltage		I _F = 60 A, T _J = 125 °C	-	1.7	-					
Deverse leekees eurrent	1	V _R = V _R rated	-	-	50					
Reverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA				
Junction capacitance C _T		V _R = 200 V	-	32	-	pF				
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH				

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1

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$			-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	130	-	ns		
		T _J = 125 °C		-	200	-			
Peak recovery current		T _J = 25 °C	I _F = 40 A dI _F /dt = 600 A/µs V _R = 400 V	-	22	-	A		
	I _{RRM}	T _J = 125 °C		-	39	-			
D	0	T _J = 25 °C		-	1610	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	4080	-			
Deveree receiver time		T _J = 25 °C		-	100	-	ns		
Reverse recovery time	t _{rr}	T _J = 125 °C		-	153	-			
Deals receiver a current		T _J = 25 °C	$I_{\rm F} = 60 {\rm A}$	-	40	-	A		
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = 1000 A/µs V _B = 800 V	-	67	-			
	0	T _J = 25 °C		-	2590	-	-0		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	6150	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.4	°C/W				
Weight			-	5.5	-	g				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style TO-247AD 2L	E5PH6012LH							

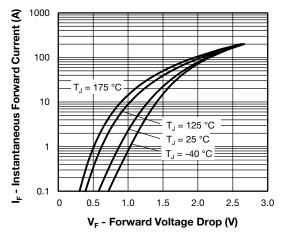


Fig. 1 - Typical Forward Voltage Drop Characteristics

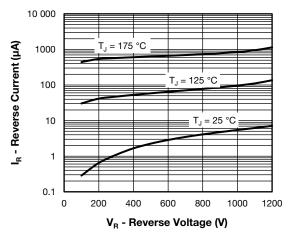
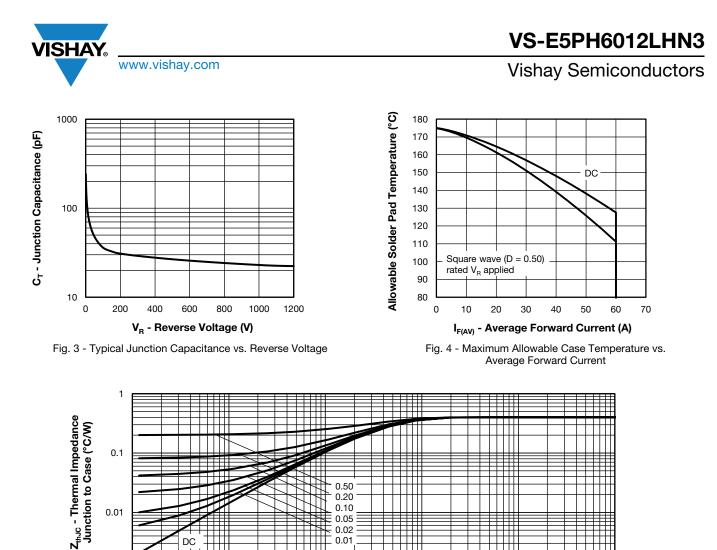


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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0.10

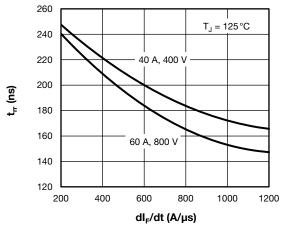
0.05 0.02

0.01

t₁ - Rectangular Pulse Duration (s) Fig. 5 - Thermal Impedance ZthJC Characteristics

0.001

0.01



DC

0.0001

0.01

0.001 0.00001

Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

7000 T_J = 125 °C 6500 60 A. 800 V 6000 5500 Q_{rr} (nC) 5000 40 A, 400 V 4500 4000 3500 3000 200 400 600 800 1000 1200 dl_F/dt (A/µs)

0.1

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Fig. 7 - Typical Stored Charge vs. dl_F/dt

Revision: 09-Nov-2022

3

Document Number: 96766

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VS-E5PH6012LHN3

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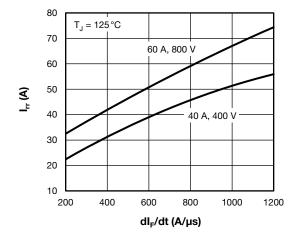


Fig. 8 - Typical Recovery Current vs. dl_F/dt

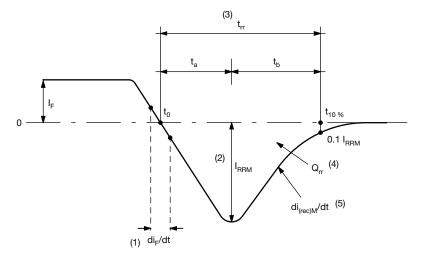


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

⁽¹⁾ di_F/dt - rate of change of current through zero crossing

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- ⁽²⁾ I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

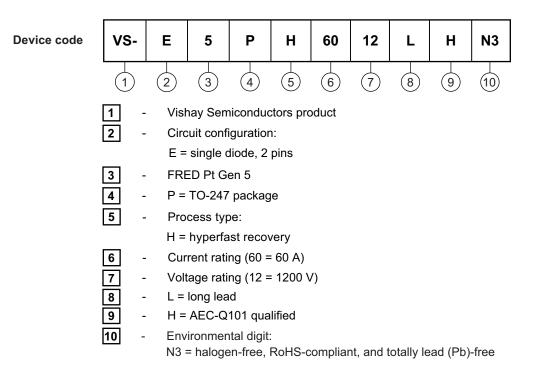
$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

⁽⁵⁾ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E5PH6012LHN3	25	500	Antistatic plastic tube					

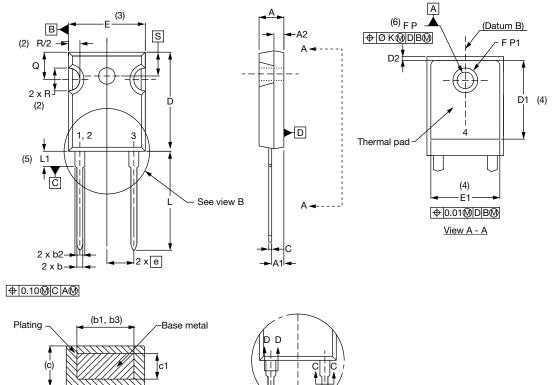
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95536						
Part marking information	www.vishay.com/doc?95648						
SPICE model	www.vishay.com/doc?97086						



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TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

(b. b2)

(4)

/	\square
	C C
Vie	<u>w B</u>

SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NUTES
А	4.65	5.31	0.183	0.209			Е	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	BSC	
b	0.99	1.40	0.039	0.055			ØК	0.2	254	0.0)10	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	BSC	
D2	0.51	1.35	0.020	0.053								

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

⁽²⁾ Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

(7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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1

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